



17 Ω, +12 V / ± 5 V / +5 V / +3 V, 8-Ch / Dual 4-Ch High Performance Analog Multiplexers

DESCRIPTION

The DG408LE, DG409LE are monolithic analog multiplexers / demultiplexers designed to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with ± 3 V to ± 8 V.

The DG408LE is an 8 channel single-ended analog multiplexer designed to connect one of eight inputs to a common output as determined by a 3 bit binary address (A₀, A₁, A₂). The DG409LE is a dual 4 channel differential analog multiplexer designed to connect one of four differential inputs to a common dual output as determined by its 2 bit binary address (A₀, A₁). Break-before-make switching action to protect against momentary crosstalk between adjacent channels.

An on channel conducts current equally well in both directions. In the off state each channel blocks voltages up to the power supply rails. An enable (EN) function allows the user to reset the multiplexer / demultiplexer to all switches off for stacking several devices. All control inputs, address (A_x) and enable (EN) are TTL compatible over the full specified operating temperature range.

The DG408LE, DG409LE feature low on-resistance, fast switching time, and low leakage. They are ideal for data acquisition, control and automation, test instrument, and healthcare products. The DG408LE, DG409LE has an internal regulator powers the logic circuit. Such design reduces device power consumption and makes them ideal for battery operated applications.

The DG408LE, DG409LE are available in TSSOP16, SOIC16, and QFN16 packages.

FEATURES

- Pin-for-pin compatibility with DG408, DG409, and DG508, DG509
- 3 V to 16 V single supply or ± 3 V to ± 8 V dual supply operation
- Low power consumption: 6 μA/max., EN = V_X = 5 V
- Lower on-resistance: R_{DS(on)} - 17 Ω typ.
- Fast switching: t_{ON} - 55 ns, t_{OFF} - 36 ns
- Break-before-make guaranteed
- Low leakage: I_{S(OFF)} - 1 nA max.
- TTL, CMOS, LV logic (3 V) compatible
- -99 dB off-isolation and -98 dB crosstalk at 100 kHz
- Low parasitic capacitances: C_{S(OFF)} = 5.5 pF, C_{D(ON)} = 35 pF (DG408LE)
- ESD Protection:
 - ± 2.5 kV human body model
 - ± 100 V machine model
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details.

BENEFITS

- High accuracy
- Single and dual power rail capacity
- Wide operating voltage range
- Simple logic interface

APPLICATIONS

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAMS AND PIN CONFIGURATIONS

DG408LE

Dual-In- Line, SOIC and TSSOP



DG409LE

Dual-In- Line, SOIC and TSSOP



QFN OUTLINE


| TRUTH TABLE (DG408LE) | | | | |
|-----------------------|----------------|----------------|----|-----------|
| A ₂ | A ₁ | A ₀ | EN | ON SWITCH |
| X | X | X | 0 | None |
| 0 | 0 | 0 | 1 | 1 |
| 0 | 0 | 1 | 1 | 2 |
| 0 | 1 | 0 | 1 | 3 |
| 0 | 1 | 1 | 1 | 4 |
| 1 | 0 | 0 | 1 | 5 |
| 1 | 0 | 1 | 1 | 6 |
| 1 | 1 | 0 | 1 | 7 |
| 1 | 1 | 1 | 1 | 8 |

| TRUTH TABLE (DG409LE) | | | |
|-----------------------|----------------|----|-----------|
| A ₁ | A ₀ | EN | ON SWITCH |
| X | X | 0 | None |
| 0 | 0 | 1 | 1 |
| 0 | 1 | 1 | 2 |
| 1 | 0 | 1 | 3 |
| 1 | 1 | 1 | 4 |

Note

- For low and high voltage levels for V_{AX} and V_{EN} consult "Digital Control" parameters for specific V+ operation.

| ORDERING INFORMATION | | | | |
|-------------------------------|--|--|------------------|-----------------------------|
| TEMP. RANGE | CONFIGURATION | PACKAGE | PART NUMBER | MIN. ORDER / PACK. QUANTITY |
| -40 °C to +85 °C Lead-free | 8 Channel Single Ended DG408LE | 16-pin TSSOP | DG408LEDQ-GE3 | Tube 360 units |
| | | | DG408LEDQ-T1-GE3 | Tape and reel, 3000 units |
| | | 16-pin SOIC | DG408LEDY-GE3 | Tube 500 units |
| | | | DG408LEDY-T1-GE3 | Tape and reel, 2500 units |
| | | 16-pin QFN (3 mm x 3 mm) Variation 2 | DG408LEDN-T1-GE4 | Tape and reel, 2500 units |
| | | Dual 4 Channel Differential DG409LE | 16-pin TSSOP | DG409LEDQ-GE3 |
| | DG409LEDQ-T1-GE3 | | | Tape and reel, 3000 units |
| | 16-pin SOIC | | DG409LEDY-GE3 | Tube 500 units |
| | | | DG409LEDY-T1-GE3 | Tape and reel, 2500 units |
| | 16-pin QFN (3 mm x 3 mm) Variation 2 | | DG409LEDN-T1-GE4 | Tape and reel, 2500 units |

Note

- T1 indicates tape and reel, -GE3 indicates lead (Pb)-free and RoHS-compliant, NO -GE3 indicates standard tin/lead finish.
- Exposed pad of QFN package can be connected to GND, V-, or left floating.



| ABSOLUTE MAXIMUM RATINGS | | | |
|---|-----------------------------------|-------------------------|------|
| PARAMETER | | LIMIT | UNIT |
| V+ to V- ^e | | 18 | V |
| GND to V- | | -18 | |
| Digital Inputs ^a , V _S , V _D | | (V-) - 0.3 to (V) + 0.3 | |
| Current (any terminal) | | 30 | mA |
| Peak Current, S or D (pulsed at 1 ms, 10 % duty cycle max.) | | 100 | |
| Storage Temperature | (D suffix) | -65 to +125 | °C |
| Power Dissipation (package) ^b | 16-pin plastic TSSOP ^c | 600 | mW |
| | 16-pin narrow SOIC ^c | 600 | |
| | 16-pin miniQFN ^d | 1385 | |
| ESD Human Body Model (HBM); per ANSI / ESDA / JEDEC [®] JS-001 | | 2500 | V |
| Latch Up Current, per JESD78D | | 300 | mA |

Notes

- a. Signals on S_x, D_x, A_x, or EN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads soldered or welded to PC board.
- c. Derate 8 mW/°C above 75 °C.
- d. Derate 17.3 mW/°C above 70 °C
- e. Also applies when V- = GND

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



| SPECIFICATIONS (Single Supply 12 V) | | | | | | | | | |
|--|-----------------------|--|--|-------------------|------------------------------|-------------------|------|---|----|
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 12 V, ± 10 %, V- = 0 V VEN = 0.8 V or 2.4 V ^f | TEMP. ^b | TYP. ^d | D SUFFIX -40 °C to +85 °C | | UNIT | | |
| | | | | | MIN. ^c | MAX. ^c | | | |
| Analog Switch | | | | | | | | | |
| Analog Signal Range ^e | V _{ANALOG} | | Full | - | 0 | 12 | V | | |
| Drain-Source On-Resistance | R _{DS(on)} | V _D = 10.8 V, V _D = 2 V or 9 V, I _S = 10 mA sequence each switch on | Room | 17 | - | 23 | Ω | | |
| | | | Full | - | - | 27 | | | |
| R _{DS(on)} Matching Between Channels ^g | ΔR _{DS} | V _D = 10.8 V, V _D = 2 V or 9 V I _S = 10 mA | Room | 1 | - | 3 | Ω | | |
| On-Resistance Flatness | R _{FLAT(on)} | | Room | 3 | - | 6.5 | | | |
| Switch Off Leakage Current ^a | I _{S(off)} | V _{EN} = 0 V, V _D = 11 V or 1 V V _S = 1 V or 11 V | Room | - | -1 | 1 | nA | | |
| | | | Full | - | -5 | 5 | | | |
| | Room | | - | -1 | 1 | | | | |
| | Full | | - | -5 | 5 | | | | |
| Channel On Leakage Current ^a | I _{D(on)} | V _S = V _D = 1 V or 11 V | Room | - | -1 | 1 | | | |
| | | | Full | - | -5 | 5 | | | |
| Digital Control | | | | | | | | | |
| Logic High Input Voltage | V _{INH} | | Full | - | 2.4 | - | V | | |
| Logic Low Input Voltage | V _{INL} | | Full | - | - | 0.8 | | | |
| Input Current ^a | I _{IN} | V _{AX} = V _{EN} = 2.4 V or 0.8 V | Full | - | -1 | 1 | μA | | |
| Dynamic Characteristics | | | | | | | | | |
| Transition Time | t _{TRANS} | V _{S1} = 8 V, V _{S8} = 0 V, (DG408LE) V _{S1b} = 8 V, V _{S4b} = 0 V, (DG409LE) see figure 2 | Room | 85 | - | 100 | ns | | |
| | | | Full | - | - | 110 | | | |
| Break-Before-Make Time | t _{OPEN} | V _{S(all)} = V _{DA} = 5 V see figure 4 | Room | 34 | 1 | - | ns | | |
| | | | Full | - | - | - | | | |
| Enable Turn-On Time | t _{ON(EN)} | V _{AX} = 0 V, V _{S1} = 5 V (DG408LE) V _{AX} = 0 V, V _{S1b} = 5 V (DG409LE) see figure 3 | Room | 55 | - | 72 | ns | | |
| | | | Full | - | - | 82 | | | |
| Enable Turn-Off Time | t _{OFF(EN)} | | Room | 36 | - | 47 | | | |
| | | | Full | - | - | 50 | | | |
| Charge Injection ^e (DG408LE) | Q | C _L = 1 nF, V _{GEN} = 6 V, R _{GEN} = 0 Ω | Room | -11 | - | - | pC | | |
| Charge Injection ^e (DG409LE) | | | Room | -10 | - | - | | | |
| Off Isolation ^{e, h} (DG408LE) | OIRR | f = 100 kHz, R _L = 50 Ω | Room | -99 | - | - | dB | | |
| Off Isolation ^{e, h} (DG409LE) | | | Room | -87 | - | - | | | |
| Crosstalk ^e (DG408LE) | X _{TALK} | | Room | -98 | - | - | | | |
| Crosstalk ^e (DG409LE) | | | Room | -109 | - | - | | | |
| Source Off Capacitance ^e (DG408LE) | C _{S(off)} | | f = 1 MHz, V _S = 0 V, V _{EN} = 0 V | Room | 5.5 | - | | - | pF |
| Source Off Capacitance ^e (DG409LE) | | | | Room | 5.5 | - | | - | |
| Drain Off Capacitance ^e (DG408LE) | C _{D(off)} | f = 1 MHz, V _D = 2.4 V, V _{EN} = 0 V | Room | 25 | - | - | pF | | |
| Drain Off Capacitance ^e (DG409LE) | | | Room | 13.5 | - | - | | | |
| Drain On Capacitance (DG408LE) | C _{D(on)} | f = 1 MHz, V _D = 0 V, V _{EN} = 2.4 V (DG409LE only) | Room | 35 | - | - | pF | | |
| Drain On Capacitance ^e (DG409LE) | | | Room | 23.5 | - | - | | | |
| Power Supplies | | | | | | | | | |
| Power Supply Range | V+ | | | - | 3 | 12 | V | | |
| Power Supply Current | I+ | V _{EN} = V _A = 0 V or 5 V | Room | 3.5 | - | 6 | μA | | |

Notes

- a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.
- g. ΔR_{DS(on)} = R_{DS(on)} max. - R_{DS(on)} min.
- h. Worst case isolation occurs on Channel 4 do to proximity to the drain pin.



| SPECIFICATIONS (Dual Supply $V_+ = 5\text{ V}$, $V_- = -5\text{ V}$) | | | | | | | |
|--|---------------|--|--------------------|-------------------|------------------------------|-------------------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_+ = 5\text{ V}$, $\pm 10\%$, $V_- = -5\text{ V}$ $V_{EN} = 0.6\text{ V}$ or 2.4 V ^f | TEMP. ^b | TYP. ^d | D SUFFIX -40 °C to +85 °C | | UNIT |
| | | | | | MIN. ^c | MAX. ^c | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^e | V_{ANALOG} | | Full | - | -5 | 5 | V |
| Drain-Source On-Resistance | $R_{DS(on)}$ | $V_D = \pm 3.5\text{ V}$, $I_S = 10\text{ mA}$ sequence each switch on | Room | 15 | - | 25 | Ω |
| | | | Full | - | - | 30 | |
| Switch Off Leakage Current ^a | $I_{S(off)}$ | $V_+ = 5.5\text{ V}$, $V_- = 5.5\text{ V}$ $V_{EN} = 0\text{ V}$, $V_D = \pm 4.5\text{ V}$, $V_S = \pm 4.5\text{ V}$ | Room | - | -1 | 1 | nA |
| | | | Full | - | -5 | 5 | |
| | $I_{D(off)}$ | | Room | - | -1 | 1 | |
| | | | Full | - | -5 | 5 | |
| Channel On Leakage Current ^a | $I_{D(on)}$ | $V_+ = 5.5\text{ V}$, $V_- = -5.5\text{ V}$ $V_{EN} = 2.4\text{ V}$, $V_D = \pm 4.5\text{ V}$, $V_S = \pm 4.5\text{ V}$ | Room | - | -1 | 1 | |
| | | | Full | - | -5 | 5 | |
| Digital Control | | | | | | | |
| Logic High Input Voltage | V_{INH} | | Full | - | 2.4 | - | V |
| Logic Low Input Voltage | V_{INL} | | Full | - | - | 0.6 | |
| Input Current ^a | I_{IN} | $V_{AX} = V_{EN} = 2.4\text{ V}$ or 0.6 V | Full | - | -1 | 1 | μA |
| Dynamic Characteristics | | | | | | | |
| Transition Time | t_{TRANS} | $V_{S1} = 3.5\text{ V}$, $V_{S8} = -3.5\text{ V}$, (DG408LE) $V_{S1b} = 3.5\text{ V}$, $V_{S4b} = -3.5\text{ V}$, (DG409LE) see figure 2 | Room | 87 | - | 100 | ns |
| | | | Full | - | - | 120 | |
| Break-Before-Make Time | t_{OPEN} | $V_{S(all)} = V_{DA} = 3.5\text{ V}$ see figure 4 | Room | 84 | 1 | - | ns |
| | | | Full | - | - | - | |
| Enable Turn-On Time | $t_{ON(EN)}$ | $V_{AX} = 0\text{ V}$, $V_{S1} = 3.5\text{ V}$ (DG408LE) $V_{AX} = 0\text{ V}$, $V_{S1b} = 3.5\text{ V}$ (DG409LE) see figure 3 | Room | 58 | - | 73 | ns |
| | | | Full | - | - | 80 | |
| Enable Turn-Off Time | $t_{OFF(EN)}$ | | Room | 31 | - | 46 | |
| | | | Full | - | - | 51 | |
| Source Off Capacitance ^e (DG408LE) | $C_{S(off)}$ | $f = 1\text{ MHz}$, $V_S = 0\text{ V}$, $V_{EN} = 0\text{ V}$ | Room | 6 | - | - | pF |
| Source Off Capacitance ^e (DG409LE) | | | Room | 5.5 | - | - | |
| Drain Off Capacitance ^e (DG408LE) | $C_{D(off)}$ | $f = 1\text{ MHz}$, $V_D = 0\text{ V}$, $V_{EN} = 0\text{ V}$ | Room | 26 | - | - | |
| Drain Off Capacitance ^e (DG409LE) | | | Room | 14 | - | - | |
| Drain On Capacitance ^e (DG408LE) | $C_{D(on)}$ | $f = 1\text{ MHz}$, $V_D = 0\text{ V}$, $V_{EN} = 2.4\text{ V}$ | Room | 36 | - | - | |
| Drain On Capacitance ^e (DG409LE) | | | Room | 24 | - | - | |

Notes

- a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.
- b. Room = 25 °C, full = as determined by the operating temperature suffix.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.
- g. $\Delta R_{DS(on)} = R_{DS(on)} \text{ max.} - R_{DS(on)} \text{ min.}$
- h. Worst case isolation occurs on channel 4 do to proximity to the drain pin.



| SPECIFICATIONS (Single Supply 5 V) | | | | | | | |
|--|-----------------------|--|--------------------|-------------------|------------------------------|-------------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, ± 10 %, V- = 0 V VEN = 0.6 V or 2.4 V ^f | TEMP. ^b | TYP. ^d | D SUFFIX -40 °C to +85 °C | | UNIT |
| | | | | | MIN. ^c | MAX. ^c | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^e | V _{ANALOG} | | Full | - | 0 | 5 | V |
| Drain-Source On-Resistance | R _{DS(on)} | V+ = 4.5 V, V _D or V _S = 1 V or 3.5 V, I _S = 5 mA | Room | 28 | - | 36 | Ω |
| | | | Full | - | - | 41 | |
| R _{DS(on)} Matching Between Channels ^g | ΔR _{DS} | V+ = 4.5 V, V _D = 1 V or 3.5 V, I _S = 5 mA | Room | 1 | - | 3 | Ω |
| On-Resistance Flatness | R _{FLAT(on)} | | Room | - | - | 4 | |
| Switch Off Leakage Current ^a | I _{S(off)} | V+ = 5.5 V, V _S = 1 V or 4 V V _D = 4 V or 1 V | Room | - | -1 | 1 | nA |
| | I _{D(off)} | | Full | - | -5 | 5 | |
| I _{D(on)} | | | Room | - | -1 | 1 | |
| | Full | | - | -5 | 5 | | |
| Channel On Leakage Current ^a | I _{D(on)} | V+ = 5.5 V, V _D = V _S = 1 V or 4 V sequence each switch on | Room | - | -1 | 1 | nA |
| | | | Full | - | -5 | 5 | |
| Digital Control | | | | | | | |
| Logic High Input Voltage | V _{INH} | V+ = 5 V | Full | - | 2.4 | - | V |
| Logic Low Input Voltage | V _{INL} | | Full | - | - | 0.6 | |
| Input Current ^a | I _{IN} | V _{AX} = V _{EN} = 2.4 V or 0.6 V | Full | - | -1 | 1 | μA |
| Dynamic Characteristics | | | | | | | |
| Transition Time | t _{TRANS} | V _{S1} = 3.5 V, V _{S8} = 0 V, (DG408LE) V _{S1b} = 3.5 V, V _{S4b} = 0 V, (DG409LE) see figure 2 | Room | 113 | - | 135 | ns |
| | | | Full | - | - | 165 | |
| Break-Before-Make Time | t _{OPEN} | V _{S(all)} = V _{DA} = 3.5 V, see figure 4 | Room | 75 | 1 | - | ns |
| | | | Full | - | - | - | |
| Enable Turn-On Time | t _{ON(EN)} | V _{AX} = 0 V, V _{S1} = 3.5 V (DG408LE) V _{AX} = 0 V, V _{S1b} = 3.5 V (DG409LE) see figure 3 | Room | 77 | - | 89 | ns |
| | | | Full | - | - | 110 | |
| Enable Turn-Off Time | t _{OFF(EN)} | | Room | 43 | - | 50 | |
| | | | Full | - | - | 53 | |
| Charge Injection ^e (DG408LE) | Q | C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 2.5 V | Room | -2 | - | - | pC |
| Charge Injection ^e (DG409LE) | | | Room | -2 | - | - | |
| Off Isolation ^{e, h} (DG408LE) | OIRR | f = 100 kHz, R _L = 50 Ω | Room | -100 | - | - | dB |
| Off Isolation ^{e, h} (DG409LE) | | | Room | -83 | - | - | |
| Crosstalk ^e (DG408LE) | X _{TALK} | | Room | -101 | - | - | |
| Crosstalk ^e (DG409LE) | | | Room | -108 | - | - | |
| Source Off Capacitance ^e (DG408LE) | C _{S(off)} | f = 1 MHz, V _S = 0 V, V _{EN} = 0 V | Room | 6.5 | - | - | pF |
| Source Off Capacitance ^e (DG409LE) | | | Room | 6.5 | - | - | |
| Drain Off Capacitance ^e (DG408LE) | C _{D(off)} | f = 1 MHz, V _D = 0 V, V _{EN} = 0 V | Room | 30 | - | - | |
| Drain Off Capacitance ^e (DG409LE) | | | Room | 16 | - | - | |
| Drain On Capacitance ^e (DG408LE) | C _{D(on)} | f = 1 MHz, V _D = 0 V, V _{EN} = 2.4 V | Room | 40 | - | - | |
| Drain On Capacitance ^e (DG409LE) | | | Room | 26.5 | - | - | |

Notes

- a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.
- b. Room = 25 °C, full = as determined by the operating temperature suffix.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.
- g. ΔR_{DS(on)} = R_{DS(on)} max. - R_{DS(on)} min.
- h. Worst case isolation occurs on channel 4 do to proximity to the drain pin.



| SPECIFICATIONS (Single Supply 3 V) | | | | | | | | | |
|---|----------------------|--|--|-------------------|------------------------------|-------------------|------|---|----|
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, ± 10 %, V- = 0 V VEN = 0.4 V or 2 V ^f | TEMP. ^b | TYP. ^d | D SUFFIX -40 °C to +85 °C | | UNIT | | |
| | | | | | MIN. ^c | MAX. ^c | | | |
| Analog Switch | | | | | | | | | |
| Analog Signal Range ^e | V _{ANALOG} | | Full | - | 0 | 3 | V | | |
| Drain-Source On-Resistance | R _{DS(on)} | V+ = 2.7 V, V _D = 0.5 or 2.2 V, I _S = 5 mA | Room | 63 | - | 80 | Ω | | |
| | | | Full | - | - | 92 | | | |
| Switch Off Leakage Current ^a | I _{S(off)} | V+ = 3.3 V, V _S = 2 or 1 V, V _D = 1 or 2 V | Room | - | -1 | 1 | nA | | |
| | | | Full | - | -5 | 5 | | | |
| | I _{D(off)} | | Room | - | -1 | 1 | | | |
| | | | Full | - | -5 | 5 | | | |
| Channel On Leakage Current ^a | I _{D(on)} | V+ = 3.3 V, V _D = V _S = 1 V or 2 V sequence each switch on | Room | - | -1 | 1 | | | |
| | | | Full | - | -5 | 5 | | | |
| Digital Control | | | | | | | | | |
| Logic High Input Voltage | V _{INH} | | Full | - | 2 | - | V | | |
| Logic Low Input Voltage | V _{INL} | | Full | - | - | 0.4 | | | |
| Input Current ^a | I _{IN} | V _{AX} = V _{EN} = 2.4 V or 0.4 V | Full | - | -1 | 1 | μA | | |
| Dynamic Characteristics | | | | | | | | | |
| Transition Time | t _{TRANS} | V _{S1} = 1.5 V, V _{S8} = 0 V, (DG408LE) V _{S1b} = 1.5 V, V _{S4b} = 0 V, (DG409LE) see figure 2 | Room | 211 | - | 275 | ns | | |
| | | | Full | - | - | 300 | | | |
| Break-Before-Make Time | t _{OPEN} | V _{S(all)} = V _{DA} = 1.5 V, see figure 4 | Room | 209 | 1 | - | ns | | |
| | | | Full | - | - | - | | | |
| Enable Turn-On Time | t _{ON(EN)} | V _{AX} = 0 V, V _{S1} = 1.5 V (DG408LE) V _{AX} = 0 V, V _{S1b} = 1.5 V (DG409LE) see figure 3 | Room | 125 | - | 150 | ns | | |
| | | | Full | - | - | 180 | | | |
| Enable Turn-Off Time | t _{OFF(EN)} | | Room | 45 | - | 75 | | | |
| | | | Full | - | - | 95 | | | |
| Charge Injection ^e (DG408LE) | Q | C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 1.5 V | Room | 0 | - | - | pC | | |
| Charge Injection ^e (DG409LE) | | | Room | -0.4 | - | - | | | |
| Off Isolation ^{e, h} (DG408LE) | OIRR | f = 100 kHz, R _L = 50 Ω | Room | -90 | - | - | dB | | |
| Off Isolation ^{e, h} (DG409LE) | | | Room | -95 | - | - | | | |
| Crosstalk ^e (DG408LE) | X _{TALK} | | Room | -95 | - | - | | | |
| Crosstalk ^e (DG409LE) | | | Room | -93 | - | - | | | |
| Source Off Capacitance ^e (DG408LE) | C _{S(off)} | | f = 1 MHz, V _S = 0 V, V _{EN} = 0 V | Room | 7 | - | | - | pF |
| Source Off Capacitance ^e (DG409LE) | | | | Room | 7 | - | | - | |
| Drain Off Capacitance ^e (DG408LE) | C _{D(off)} | f = 1 MHz, V _D = 0 V, V _{EN} = 0 V | Room | 33 | - | - | | | |
| Drain Off Capacitance ^e (DG409LE) | | | Room | 18 | - | - | | | |
| Drain On Capacitance ^e (DG408LE) | C _{D(on)} | f = 1 MHz, V _D = 0 V, V _{EN} = 2 V | Room | 43 | - | - | | | |
| Drain On Capacitance ^e (DG409LE) | | | Room | 28 | - | - | | | |

Notes

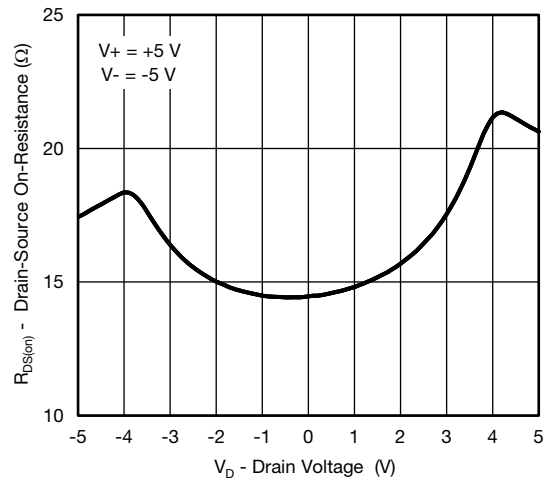
- a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.
- b. Room = 25 °C, full = as determined by the operating temperature suffix.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.
- g. ΔR_{DS(on)} = R_{DS(on)} max. - R_{DS(on)} min.
- h. Worst case isolation occurs on channel 4 do to proximity to the drain pin.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



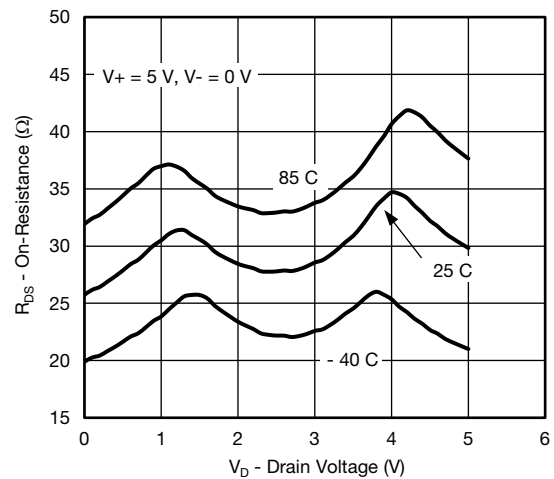
R_{DS(on)} vs. V_D and Power Supply



R_{DS(on)} vs. V_D and Power Supply



R_{DS(on)} vs. V_D and Temperature (Dual Supply)



R_{DS(on)} vs. V_D and Temperature



Input Threshold vs. V₊ Supply Voltage



Switching Time vs. Supply Voltage



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Leakage Current vs. Analog Voltage



Charge Injection vs. Analog Voltage (DG408LE)



Charge Injection vs. Analog Voltage (DG409LE)



Insertion Loss, Off Isolation, and Crosstalk vs. Frequency



Drain/Source Capacitance vs. Analog Voltage (DG408LE)

SCHEMATIC DIAGRAM (Typical Channel)



Fig. 1

TEST CIRCUITS



Fig. 2 - Transition Time

TEST CIRCUITS



Fig. 3 - Enable Switching Time



Fig. 4 - Break-Before-Make Interval

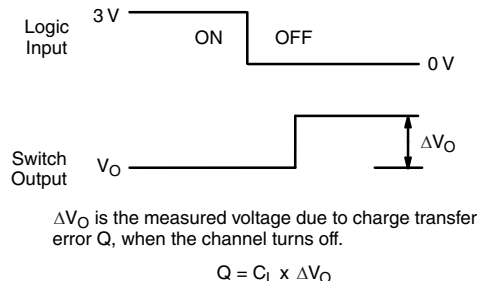
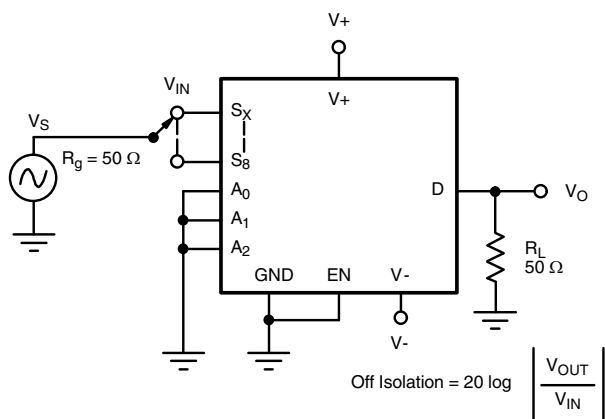
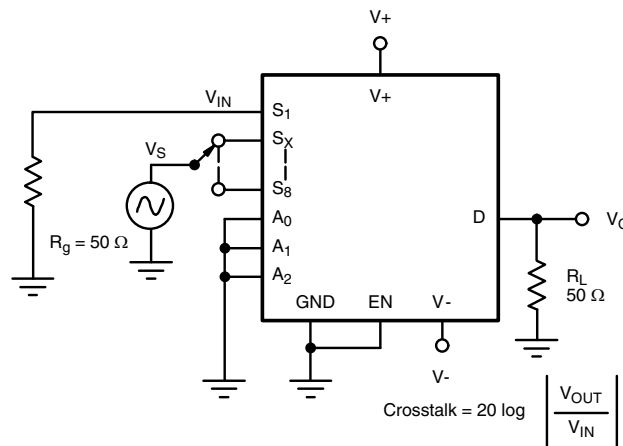
TEST CIRCUITS

Fig. 5 - Charge Injection

Fig. 6 - Off Isolation

Fig. 7 - Crosstalk

Fig. 8 - Insertion Loss

Fig. 9 - Source Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?78084.



SOIC (NARROW): 16-LEAD
JEDEC Part Number: MS-012



| Dim | MILLIMETERS | | INCHES | |
|----------------|-------------|-------|-----------|-------|
| | Min | Max | Min | Max |
| A | 1.35 | 1.75 | 0.053 | 0.069 |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 |
| B | 0.38 | 0.51 | 0.015 | 0.020 |
| C | 0.18 | 0.23 | 0.007 | 0.009 |
| D | 9.80 | 10.00 | 0.385 | 0.393 |
| E | 3.80 | 4.00 | 0.149 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| L | 0.50 | 0.93 | 0.020 | 0.037 |
| ∅ | 0° | 8° | 0° | 8° |

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



QFN-16 Lead (3 x 3)



Notes

- (1) All dimensions are in millimeters.
- (2) N is the total number of terminals.
- (3) Dimension b applies to metallized terminal and is measured between 0.25 and 0.30 mm from terminal tip.
- (4) Coplanarity applies to the exposed heat sink slug as well as the terminal.
- (5) The pin #1 identifier may be either a mold or marked feature, it must be located within the zone indicated.

| DIM. | VARIATION 1 | | | | | | VARIATION 2 | | | | | |
|------|-------------|------|------|-----------|-------|-------|-------------|------|------|-----------|-------|-------|
| | MILLIMETERS | | | INCHES | | | MILLIMETERS | | | INCHES | | |
| | MIN. | NOM | MAX. | MIN. | NOM | MAX. | MIN. | NOM | MAX. | MIN. | NOM | MAX. |
| A | 0.80 | 0.90 | 1.00 | 0.031 | 0.035 | 0.039 | 0.80 | 0.90 | 1.00 | 0.031 | 0.035 | 0.039 |
| b | 0.18 | 0.23 | 0.30 | 0.007 | 0.009 | 0.012 | 0.18 | 0.25 | 0.30 | 0.007 | 0.010 | 0.012 |
| D | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| D2 | 1.00 | 1.15 | 1.25 | 0.039 | 0.045 | 0.049 | 1.50 | 1.70 | 1.80 | 0.059 | 0.067 | 0.071 |
| E | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 | 2.90 | 3.00 | 3.10 | 0.114 | 0.118 | 0.122 |
| E2 | 1.00 | 1.15 | 1.25 | 0.039 | 0.045 | 0.049 | 1.50 | 1.70 | 1.80 | 0.059 | 0.067 | 0.071 |
| e | 0.50 BSC | | | 0.020 BSC | | | 0.50 BSC | | | 0.020 BSC | | |
| L | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 |

ECN: T16-0233-Rev. D, 09-May-16
DWG: 5899

TSSOP: 16-LEAD



| Symbols | DIMENSIONS IN MILLIMETERS | | |
|---------|---------------------------|-------|------|
| | Min | Nom | Max |
| A | - | 1.10 | 1.20 |
| A1 | 0.05 | 0.10 | 0.15 |
| A2 | - | 1.00 | 1.05 |
| B | 0.22 | 0.28 | 0.38 |
| C | - | 0.127 | - |
| D | 4.90 | 5.00 | 5.10 |
| E | 6.10 | 6.40 | 6.70 |
| E1 | 4.30 | 4.40 | 4.50 |
| e | - | 0.65 | - |
| L | 0.50 | 0.60 | 0.70 |
| L1 | 0.90 | 1.00 | 1.10 |
| y | - | - | 0.10 |
| θ1 | 0° | 3° | 6° |

ECN: S-61920-Rev. D, 23-Oct-06
 DWG: 5624



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.